

EVVOSEMI[®]

THINK CHANGE DO



ESD



TVS



MOS



LDO



Diode



Sensor



DC-DC

Product Specification

▶ Domestic	Part Number	L78LxxABD
▶ Overseas	Part Number	L78LxxABD
▶ Equivalent	Part Number	L78LxxABD

EV is the abbreviation of name EVVO

LINEAR INTEGRATED CIRCUIT

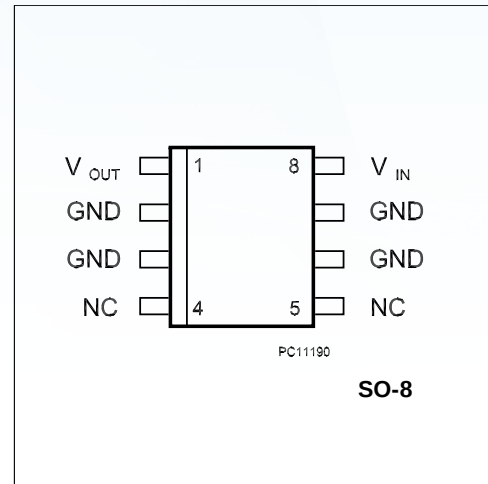
3-TERMINAL 0.1A POSITIVE VOLTAGE REGULATORS

DESCRIPTION

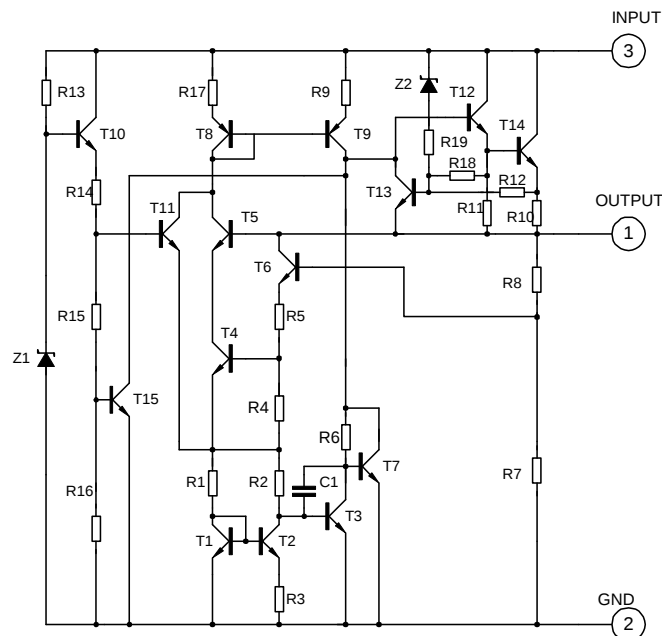
The L78LXXABD series of fixed voltage monolithic integrated circuit voltage regulators are suitable for applications that required supply up to 100mA.

FEATURE

- *Maximum output current of 100mA
- *Output voltage of 5V,6V,8V,9V,10V,12V,15V and 24V
- *Thermal overload protection
- *Short circuit current limiting



BLOCK DIAGRAM



ABSOLUTE MAXIMUM RATINGS (Operating temperature range applies unless otherwise specified)

CHARACTERISTICS	SYMBOL	VALUE	UNITS
Input voltage(for Vo=5,8V)	V _I	30	V
(for Vo=12,15V)	V _I	35	V
High power dissipation	P _d	700	mW
Operating Junction Temperature Range	T _{OPR}	-20~+120	°C
Storage Temperature Range	T _{STG}	-55~+150	°C

L78L05ABD ELECTRICAL CHARACTERISTICS

 (V_I=10V, I_o=40mA, 0<T_j<125°C, C₁=0.33μF, C_o=0.1μF, unless otherwise specified)(Note 1)

Characteristic	Symbol	Test conditions	MIN	TYP	MAX	UNIT
Output Voltage	V _o	T _j =25°C	4.8	5.0	5.2	V
		7V≤V _I ≤20V, I _o =1mA~40mA	4.75		5.25	V
		7V≤V _I ≤V _{MAX} , I _o =1mA~70mA	4.75		5.25	V (note 2)
Output Voltage(note 3)	V _o	T _j =25°C	4.9	5.0	5.1	V
		7V≤V _I ≤20V, I _o =1mA~40mA	4.85		5.15	V
		7V≤V _I ≤V _{MAX} , I _o =1mA~70mA	4.85		5.15	V (note 2)
Load Regulation	ΔV _o	T _j =25°C, I _o =1mA~100mA		11	60	mV
		T _j =25°C, I _o =1mA~40mA		5.0	30	mV
Line regulation	ΔV _o	7V≤V _I ≤20V, T _j =25°C		8	150	mV
		8V≤V _I ≤20V, T _j =25°C		6	100	mV
Quiescent Current	I _q			2.0	5.5	mA
Quiescent Current Change	ΔI _q	8V≤V _I ≤20V			1.5	mA
	ΔI _q	1mA≤V _I ≤40mA			0.1	mA
Output Noise Voltage	V _N	10Hz≤f≤100kHz		40		μV
Temperature coefficient of V _o	ΔV _o /ΔT	I _o =5mA		0.65		mV/°C
Ripple Rejection	RR	8V≤V _I ≤20V, f=120Hz, T _j =25°C	40	49		dB
Dropout Voltage	V _d	T _j =25°C		1.7		V

L78L06ABD ELECTRICAL CHARACTERISTICS

 (V_I=12V, I_O=40mA, 0<T_j<125°C, C₁=0.33μF, C_o=0.1μF, unless otherwise specified)(Note 1)

Characteristic	Symbol	Test conditions	MIN	TYP	MAX	UNIT
Output Voltage	V _O	T _j =25°C	5.75	6.0	6.25	V
		8.5V≤V _I ≤20V, I _O =1mA~40mA	5.7		6.3	V
		8.5V≤V _I ≤V _{MAX} , I _O =1mA~70mA	5.7		6.3	V (note 2)
Output Voltage(note 3)	V _O	T _j =25°C	5.88	6.0	6.12	V
		8.5V≤V _I ≤20V, I _O =1mA~40mA	5.82		6.18	V
		8.5V≤V _I ≤V _{MAX} , I _O =1mA~70mA	5.82		6.18	V (note 2)
Load Regulation	ΔV _O	T _j =25°C, I _O =1mA~100mA		12.8	80	mV
		T _j =25°C, I _O =1mA~70mA		5.8	40	mV
Line regulation	ΔV _O	8.5V≤V _I ≤20V, T _j =25°C		64	175	mV
		9V≤V _I ≤20V, T _j =25°C		54	125	mV
Quiescent Current	I _q			2.0	5.5	mA
Quiescent Current Change	ΔI _q	9V≤V _I ≤20V			1.5	mA
	ΔI _q	1mA≤V _I ≤40mA			0.1	mA
Output Noise Voltage	V _N	10Hz≤f≤100kHz		49		μV
Temperature coefficient of V _O	ΔV _O /ΔT	I _O =5mA		0.75		mV/°C
Ripple Rejection	RR	10V≤V _I ≤20V, f=120Hz, T _j =25°C	38	46		dB
Dropout Voltage	V _d	T _j =25°C		1.7		V

L78L08ABD ELECTRICAL CHARACTERISTICS

(VI=14V, IO=40mA, 0<Tj<125°C, C1=0.33μF, Co=0.1μF, unless otherwise specified)(Note 1)

Characteristic	Symbol	Test conditions	MIN	TYP	MAX	UNIT
Output Voltage	Vo	Tj=25°C	7.7	8.0	8.3	V
		10.5V≤Vi≤23V, Io=1mA~40mA	7.6		8.4	V
		10.5V≤Vi≤VMAX, Io=1mA~70mA	7.6		8.4	V (note 2)
Output Voltage(note 3)	Vo	Tj=25°C	7.84	8.0	8.16	V
		10.5V≤Vi≤23V, Io=1mA~40mA	7.76		8.24	V
		10.5V≤Vi≤VMAX, Io=1mA~70mA	7.76		8.24	V (note 2)
Load Regulation	ΔVo	Tj=25°C, Io=1mA~100mA		15	80	mV
Line regulation	ΔVo	Tj=25°C, Io=1mA~70mA		8.0	40	mV
		10.5V≤Vi≤23V, Tj=25°C		10	175	mV
		11V≤Vi≤23V, Tj=25°C		8	125	mV
Quiescent Current	Iq			2.0	5.5	mA
Quiescent Current Change	ΔIq	11V≤Vi≤23V			1.5	mA
	ΔIq	1mA≤Vi≤40mA			0.1	mA
Output Noise Voltage	VN	10Hz≤f≤100kHz		49		μV
Temperature coefficient of Vo	ΔVo/ΔT	Io=5mA		0.75		mV/°C
Ripple Rejection	RR	11V≤Vi≤23V, f=120Hz, Tj=25°C	36	45		dB
Dropout Voltage	Vd	Tj=25°C		1.7		V

L78L09ABD ELECTRICAL CHARACTERISTICS

(VI=15V, IO=40mA, 0<Tj<125°C, C1=0.33μF, Co=0.1μF, unless otherwise specified)(Note 1)

Characteristic	Symbol	Test conditions	MIN	TYP	MAX	UNIT
Output Voltage	Vo	Tj=25°C	8.64	9.0	9.36	V
		11.5V≤Vi≤24V, Io=1mA~40mA	8.55		9.45	V
		11.5V≤Vi≤VMAX, Io=1mA~70mA	8.55		9.45	V (note 2)
Output Voltage(note 3)	Vo	Tj=25°C	8.82	9.0	9.18	V
		11.5V≤Vi≤24V, Io=1mA~40mA	8.73		9.27	V
		11.5V≤Vi≤VMAX, Io=1mA~70mA	8.73		9.27	V (note 2)
Load Regulation	ΔVo	Tj=25°C, Io=1mA~100mA		20	90	mV
		Tj=25°C, Io=1mA~40mA		10	45	mV
Line regulation	ΔVo	11.5V≤Vi≤24V, Tj=25°C		90	200	mV
		13V≤Vi≤24V, Tj=25°C		100	150	mV
Quiescent Current	Iq			2.0	5.5	mA
Quiescent Current Change	ΔIq	13V≤Vi≤24V			1.5	mA
	ΔIq	1mA≤Vi≤40mA			0.1	mA
Output Noise Voltage	VN	10Hz≤f≤100kHz		49		μV
Temperature coefficient of Vo	ΔVo/ΔT	Io=5mA		0.75		mV/°C
Ripple Rejection	RR	12V≤Vi≤23V, f=120Hz, Tj=25°C	36	44		dB
Dropout Voltage	Vd	Tj=25°C		1.7		V

L78L12ABD ELECTRICAL CHARACTERISTICS

(VI=19V, IO=40mA, 0<Tj<125°C, C1=0.33μF, Co=0.1μF, unless otherwise specified)(Note 1)

Characteristic	Symbol	Test conditions	MIN	TYP	MAX	UNIT
Output Voltage	Vo	Tj=25°C	11.5	12	12.6	V
		14.5V≤Vi≤27V, IO=1mA~40mA	11.4		12.6	V
		14.5V≤Vi≤VMAX, IO=1mA~70mA	11.4		12.6	V (note 2)
Output Voltage(note 3)	Vo	Tj=25°C	11.76	12.0	12.24	V
		14.5V≤Vi≤27V, IO=1mA~40mA	11.64		12.36	V
		14.5V≤Vi≤VMAX, IO=1mA~70mA	11.64		12.36	V (note 2)
Load Regulation	ΔVo	Tj=25°C, IO=1mA~100mA		25	150	mV
		Tj=25°C, IO=1mA~40mA		12	75	mV
Line regulation	ΔVo	14.5V≤Vi≤27V, Tj=25°C		25	300	mV
		16V≤Vi≤27V, Tj=25°C		20	250	mV
Quiescent Current	Iq			2.0	5.5	mA
Quiescent Current Change	ΔIq	16V≤Vi≤27V			1.5	mA
	ΔIq	1mA≤Vi≤40mA			0.1	mA
Output Noise Voltage	VN	10Hz≤f≤100kHz		80		μV
Temperature coefficient of Vo	ΔVo/ΔT	IO=5mA		1.0		mV/°C
Ripple Rejection	RR	15V≤Vi≤25V, f=120Hz, Tj=25°C	36	42		dB
Dropout Voltage	Vd	Tj=25°C		1.7		V

L78L15ABD ELECTRICAL CHARACTERISTICS

(VI=23V, Io=40mA, 0<Tj<125°C, C1=0.33μF, Co=0.1μF, unless otherwise specified)(Note 1)

Characteristic	Symbol	Test conditions	MIN	TYP	MAX	UNIT
Output Voltage	Vo	Tj=25°C	14.4	15	15.6	V
		17.5V≤Vi≤30V, Io=1mA~40mA	14.25		15.75	V
		17.5V≤Vi≤VMAX, Io=1mA~70mA	14.25		15.75	V (note 2)
Output Voltage(note 3)	Vo	Tj=25°C	14.7	15.0	15.3	V
		17.5V≤Vi≤30V, Io=1mA~40mA	14.55		15.45	V
		17.5V≤Vi≤VMAX, Io=1mA~70mA	14.55		15.45	V (note 2)
Load Regulation	ΔVo	Tj=25°C, Io=1mA~100mA		20	150	mV
Line regulation	ΔVo	Tj=25°C, Io=1mA~70mA		25	150	mV
		17.5V≤Vi≤30V, Tj=25°C		25	150	mV
		20V≤Vi≤30V, Tj=25°C		15	75	mV
Quiescent Current	Iq			2.2	6.0	mA
Quiescent Current Change	ΔIq	20V≤Vi≤30V			1.5	mA
	ΔIq	1mA≤Vi≤40mA			0.1	mA
Output Noise Voltage	VN	10Hz≤f≤100kHz		90		μV
Temperature coefficient of Vo	ΔVo/ΔT	Io=5mA		1.3		mV/°C
Ripple Rejection	RR	18.5V≤Vi≤28.5V, f=120Hz, Tj=25°C	33	39		dB
Dropout Voltage	Vd	Tj=25°C		1.7		V

L78L18ABD ELECTRICAL CHARACTERISTICS

(VI=27V, IO=40mA, 0<Tj<125°C, C1=0.33μF, Co=0.1μF, unless otherwise specified)(Note 1)

Characteristic	Symbol	Test conditions	MIN	TYP	MAX	UNIT
Output Voltage	Vo	Tj=25°C	17.3	18	18.7	V
		21V≤Vi≤33V, IO=1mA~40mA	17.1		18.9	V
		21V≤Vi≤VMAX, IO=1mA~70mA	17.1		18.9	V (note 2)
Output Voltage(note 3)	Vo	Tj=25°C	17.64	18.0	18.36	V
		21V≤Vi≤33V, IO=1mA~40mA	17.46		18.54	V
		21V≤Vi≤VMAX, IO=1mA~70mA	17.46		18.54	V (note 2)
Load Regulation	ΔVo	Tj=25°C, IO=1mA~100mA		30	170	mV
		Tj=25°C, IO=1mA~40mA		15	85	mV
Line regulation	ΔVo	21V≤Vi≤33V, Tj=25°C		145	300	mV
		22V≤Vi≤33V, Tj=25°C		135	250	mV
Quiescent Current	Iq			2.2	6.0	mA
Quiescent Current Change	ΔIq	21V≤Vi≤33V			1.5	mA
	ΔIq	1mA≤Vi≤40mA			0.1	mA
Output Noise Voltage	VN	10Hz≤f≤100kHz		150		μV
Temperature coefficient of Vo	ΔVo/ΔT	IO=5mA		1.8		mV/°C
Ripple Rejection	RR	23V≤Vi≤33V, f=120Hz, Tj=25°C	32	38		dB
Dropout Voltage	Vd	Tj=250°C		1.7		V

L78L24ABD ELECTRICAL CHARACTERISTICS

(VI=33V, Io=40mA, 0<Tj<125°C, C1=0.33μF, Co=0.1μF, unless otherwise specified)(Note 1)

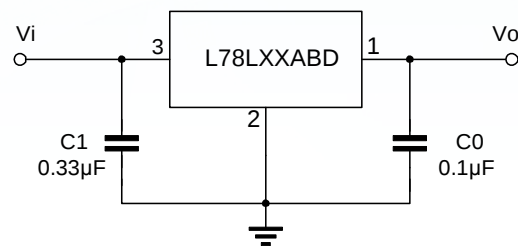
Characteristic	Symbol	Test conditions	MIN	TYP	MAX	UNIT
Output Voltage	Vo	Tj=25°C	23	24	25	V
		27V≤Vi≤38V, Io=1mA~40mA	22.8		25.2	V
		27V≤Vi≤VMAX, Io=1mA~70mA	22.8		25.2	V (note 2)
Output Voltage(note 3)	Vo	Tj=25°C	23.5	24	24.5	V
		27V≤Vi≤38V, Io=1mA~40mA	23.25		24.75	V
		27V≤Vi≤VMAX, Io=1mA~70mA	23.25		24.75	V (note 2)
Load Regulation	ΔVo	Tj=25°C, Io=1mA~100mA		40	200	mV
		Tj=25°C, Io=1mA~40mA		20	100	mV
Line regulation	ΔVo	27V≤Vi≤38V, Tj=25°C		160	300	mV
		28V≤Vi≤38V, Tj=25°C		150	250	mV
Quiescent Current	Iq			2.2	6.0	mA
Quiescent Current Change	ΔIq	27V≤Vi≤38V			1.5	mA
	ΔIq	1mA≤Vi≤40mA			0.1	mA
Output Noise Voltage	Vn	10Hz≤f≤100kHz		200		μV
Temperature coefficient of Vo	ΔVo/ΔT	Io=5mA		2.0		mV/°C
Ripple Rejection	RR	27V≤Vi≤38V, f=120Hz, Tj=25°C	30	37		dB
Dropout Voltage	Vd	Tj=25°C		1.7		V

Note 1: The Maximum steady state usable output current and input voltage are very dependent on the heating sinking and/or lead temperature length of the package. The data above represent pulse test conditions with junction temperatures as indicated at the initiation of test.

Note 2: Power dissipation<0.75W.

Note 3: Output voltage of 78LXXA.

TYPICAL APPLICATION



Note 1: To specify an output voltage, substitute voltage value for "XX".

Note 2: Bypass capacitors are recommended for optimum stability and transient response and should be located as close as possible to the regulators.

Fig .1 L78L05A/12 Output Voltage vs Ambient Temperature

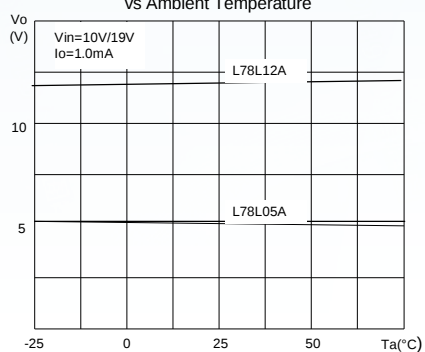


Fig 2 L78 L05A/12 Quiescent Current vs Output Current

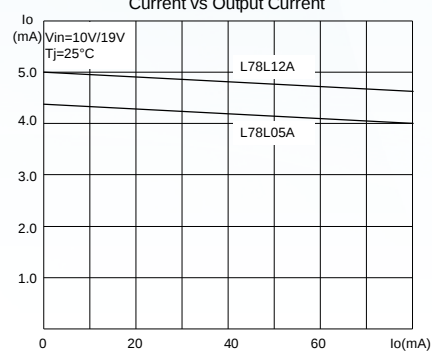


Fig.3 L78L05A Quiescent Current vs Input

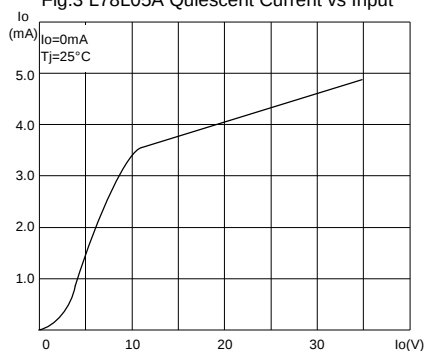


Fig.4 L78L05A /12/24 Thermal Shutdown

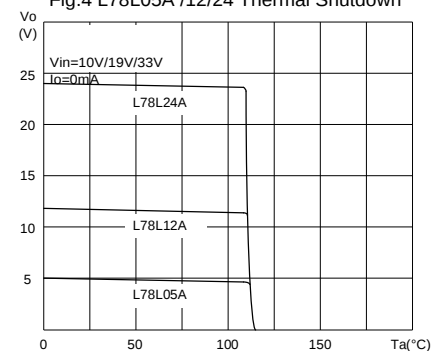


Fig.5 L78L05A/12/24 Output Characteristics

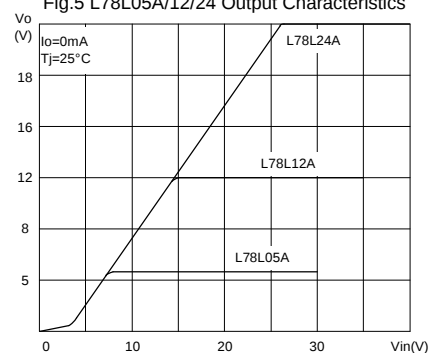
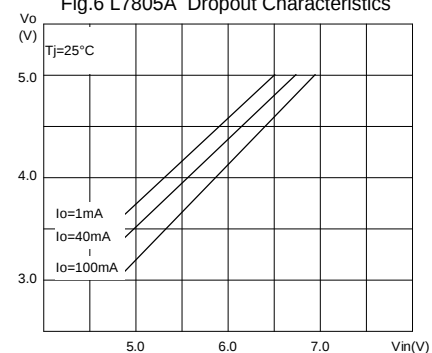
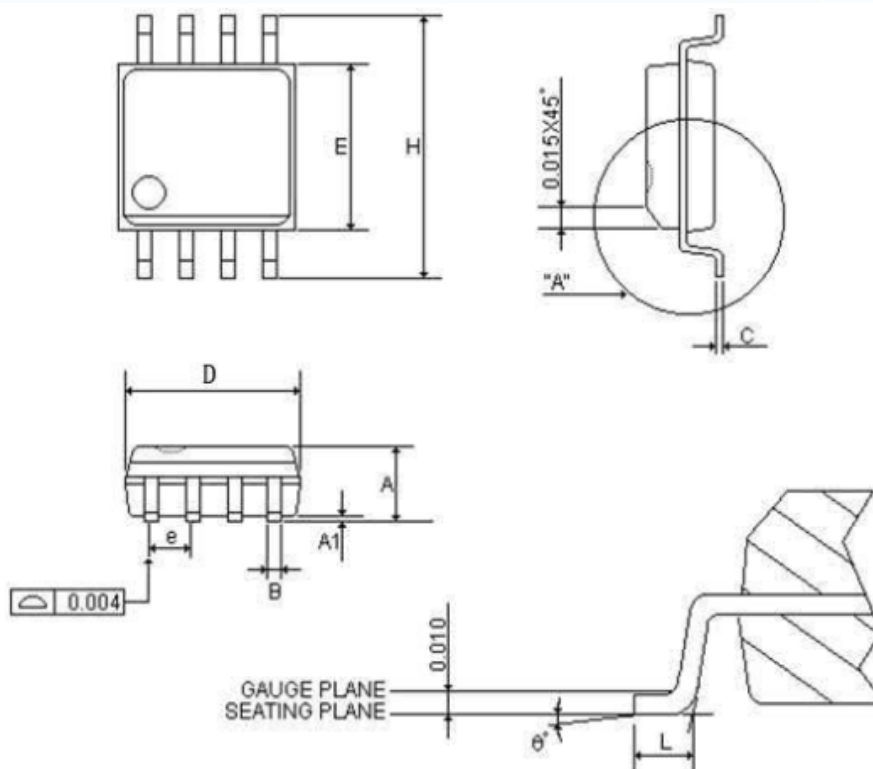


Fig.6 L7805A Dropout Characteristics



PACKAGE OUTLINE

SOP 8



SYMBOLS	MIN	NOR	MAX	MIN	NOR	MAX
	(inch)			(mm)		
A	0.058	0.064	0.068	1.4732	1.6256	1.7272
A1	0.004	-	0.010	0.1016	-	0.254
B	0.013	0.016	0.020	0.3302	0.4064	0.508
C	0.0075	0.008	0.0098	0.1905	0.2032	0.2490
D	0.186	0.191	0.196	5.9944	6.1214	6.1976
E	0.150	0.154	0.157	3.81	3.9116	3.9878
e	-	0.050	-	-	1.27	-
H	0.228	0.236	0.244	5.7912	5.9944	6.1976
L	0.015	0.025	0.050	0.381	0.635	1.27
0°	0°	-	8°	0°	-	8°

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